

## **DATASHEET**

# 4 PIN DIP PHOTOTRANSISTOR PHOTOCOUPLER EL817-G Series



#### Features:

- Compliance Halogens Free (Br < 900 ppm, Cl < 900 ppm, Br+Cl < 1500 ppm)
- Current transfer ratio
  (CTR: 50~600% at IF = 5mA, VcE = 5V)
  High isolation voltage between input
- High isolation voltage between input and output (Viso = 5000Vrms)
- Creepage distance > 7.62mm
- Operating temperature up to +110°C
- Compact small outline package
- Compliance with EU REACH.
- •The product itself will remain within RoHS compliant version
- UL and cUL approved(No.E214129)
- VDE approved (No.132249)
- SEMKO approved
- NEMKO approved
- DEMKO approved
- FIMKO approved
- CQC approved

#### **Description**

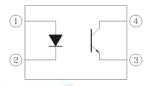
The EL817-G series of devices each consist of an infrared emitting diodes, optically coupled to a phototransistor detector.

They are packaged in a 4-pin DIP package and available in wide-lead spacing and SMD option.

## **Applications**

- Programmable controllers
- System appliances, measuring instruments
- Telecommunication equipments
- Home appliances, such as fan heaters, etc.
- Signal transmission between circuits of different potentials and impedances

## <u>Schematic</u>



#### Pin Configuration

- 1. Anode
- 2. Cathode
- 3. Emitter
- 4. Collector



## Absolute Maximum Ratings (Ta=25°C)

Parameter	Symbol	Rating	Unit
Forward current	$I_{F}$	60	mA
Peak forward current (1us, pulse)	I <sub>FP</sub>	1	А
Reverse voltage	V <sub>R</sub>	6	V
Power dissipation	D	100	mW
Derating factor (above T <sub>a</sub> = 100°C)	$P_{D}$	2.9	mW/°C
Power dissipation	D	150	mW
Derating factor (above T <sub>a</sub> = 100°C)	PC	5.8	mW/°C
Collector current	I <sub>C</sub>	50	mA
Collector-Emitter voltage	V <sub>CEO</sub>	80	V
Emitter-Collector voltage	$V_{\text{ECO}}$	7	V
Dissipation	P <sub>TOT</sub>	200	mW
age*1	V <sub>ISO</sub>	5000	V rms
mperature	T <sub>OPR</sub>	-55 to 110	°C
perature	T <sub>STG</sub>	-55 to 125	°C
mperature* <sup>2</sup>	T <sub>SOL</sub>	260	°C
	Forward current  Peak forward current (1us, pulse)  Reverse voltage  Power dissipation Derating factor (above T <sub>a</sub> = 100°C)  Power dissipation Derating factor (above T <sub>a</sub> = 100°C)  Collector current  Collector-Emitter voltage  Emitter-Collector voltage  Dissipation  age*1  mperature	Forward current $I_F$ Peak forward current (1us, pulse) $I_{FP}$ Reverse voltage $V_R$ Power dissipation $P_D$ Power dissipation $P_D$ Power dissipation $P_D$ Power dissipation $P_C$ Collector (above $T_a = 100^{\circ}C$ )  Collector current $I_C$ Collector-Emitter voltage $V_{CEO}$ Emitter-Collector voltage $V_{ECO}$ Dissipation $P_{TOT}$ age*1 $V_{ISO}$ mperature $T_{OPR}$	Forward current $I_F$ 60  Peak forward current (1us, pulse) $I_{FP}$ 1  Reverse voltage $V_R$ 6  Power dissipation Derating factor (above $T_a = 100^{\circ}\text{C}$ ) $P_D$ $0$ $0$ $0$ $0$ $0$ $0$ $0$ $0$ $0$ $0$

## Notes:

<sup>\*1</sup> AC for 1 minute, R.H.=  $40 \sim 60\%$  R.H. In this test, pins 1, 2 are shorted together, and pins 3, 4 are shorted together.

<sup>\*2</sup> For 10 seconds



## Electro-Optical Characteristics (Ta=25°C unless specified otherwise)

Input

Parameter	Symbol	Min.	Тур.	Max.	Unit	Condition
Forward Voltage	$V_{F}$	-	1.2	1.4	V	$I_F = 20 \text{mA}$
Reverse Current	I <sub>R</sub>	-	-	10	μA	$V_R = 4V$
Input capacitance	C <sub>in</sub>	-	30	250	pF	V = 0, $f = 1kHz$

Output

Parameter	Symbol	Min	Тур.	Max.	Unit	Condition
Collector-Emitter dark	lana	_	_	100	nA	$V_{CE} = 20V, I_{F} = 0mA$
current	ICEO			100	11/3	VCE = 20 V, IF = 0111A
Collector-Emitter	$BV_CEO$	80	_	_	V	$I_{\rm C} = 0.1  \rm mA$
breakdown voltage	PACEO	00	_	_	V	IC = 0. IIIIA
Emitter-Collector	D\/	7	_	_	V	L = 0.1mΛ
breakdown voltage	$BV_{ECO}$	,	-	-	V	$I_E = 0.1 \text{mA}$

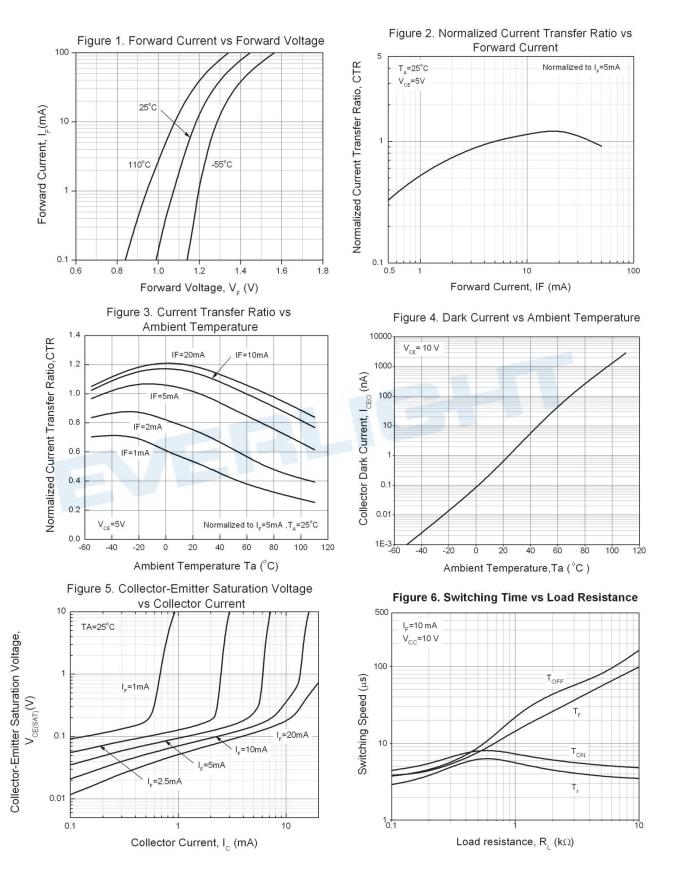
**Transfer Characteristics** 

Para	meter	Symbol	Min	Тур.	Max.	Unit	Condition
	EL817		50		600		
	EL817A		80	_	160		
Current	EL817B		130	-	260		
Transfer	EL817C	CTR	200	-	400	%	$I_F = 5mA$ , $V_{CE} = 5V$
ratio	EL817D		300	-	600		
	EL817X		100	-	200		
	EL817Y		150	-	300		
Collector-E saturation v		$V_{\text{CE(sat)}}$	-	0.1	0.2	V	$I_F = 20\text{mA}$ , $I_C = 1\text{mA}$
Isolation re	sistance	R <sub>IO</sub>	5×10 <sup>10</sup>	-	-	Ω	V <sub>IO</sub> = 500Vdc, 40~60% R.H.
Floating ca	pacitance	$C_{IO}$	-	0.6	1.0	pF	$V_{IO} = 0$ , $f = 1MHz$
Cut-off freq	uency	fc	-	80	-	kHz	$V_{CE} = 5V$ , $I_{C} = 2mA$ $R_{L} = 100\Omega$ , $-3dB$
Rise time		t <sub>r</sub>	-	6	18	μs	$V_{CE} = 2V, I_{C} = 2mA,$
Fall time		t <sub>f</sub>	-	8	18	μs	$R_L = 100\Omega$

<sup>\*</sup> Typical values at T<sub>a</sub> = 25°C



## **Typical Electro-Optical Characteristics Curves**





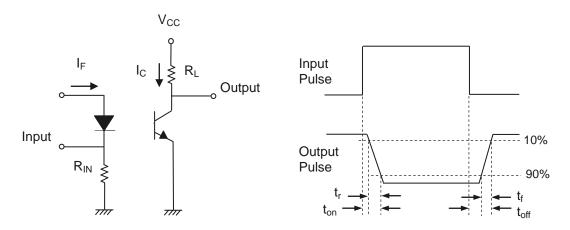


Figure 7. Switching Time Test Circuit & Waveforms





## **Order Information**

#### **Part Number**

## EL817X(Y)(Z)-FVG

#### Note

X = Lead form option (S1, S2, M or none) Y = CTR Rank (A, B, C, D, X, Y or none)

Z = Tape and reel option (TU, TD or none)

F = Lead frame option (F: Iron, None: copper)

V = VDE safety (optional)

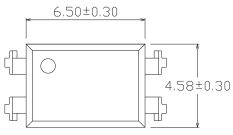
G = Halogens free

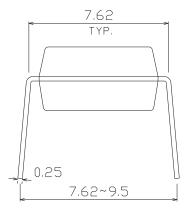
Option	Description	Packing quantity
None	Standard DIP-4	100 units per tube
М	Wide lead bend (0.4 inch spacing)	100 units per tube
S1 (TU)	Surface mount lead form (low profile) + TU tape & reel option	1500 units per reel
S1 (TD)	Surface mount lead form (low profile) + TD tape & reel option	1500 units per reel
S2 (TU)	Surface mount lead form (low profile) + TU tape & reel option	2000 units per reel
S2 (TD)	Surface mount lead form (low profile) + TD tape & reel option	2000 units per reel

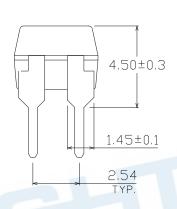


## Package Dimension (Dimensions in mm)

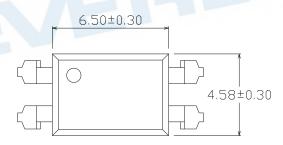
## **Standard DIP Type**

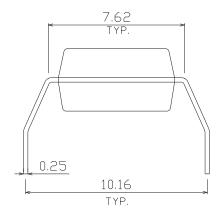


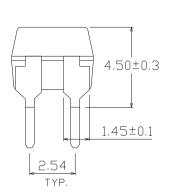




## **Option M Type**

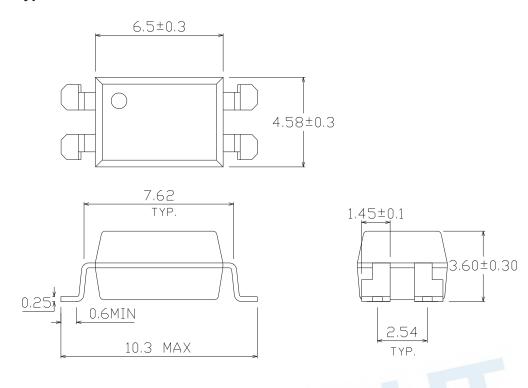




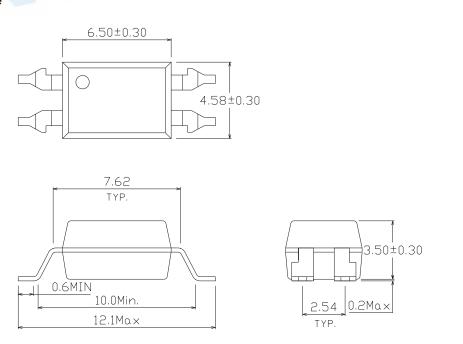




## **Option S1 Type**



## **Option S2 Type**

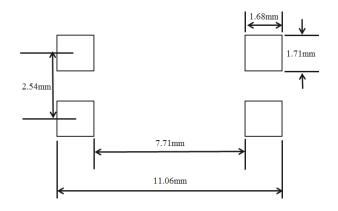


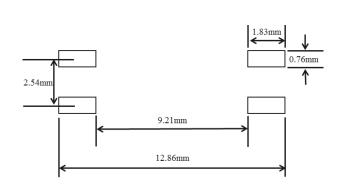


## Recommended pad layout for surface mount leadform

## For S1 option

## For S2 option





#### **Notes**

Suggested pad dimension is just for reference only. Please modify the pad dimension based on individual need.

## **Device Marking**



#### **Notes**

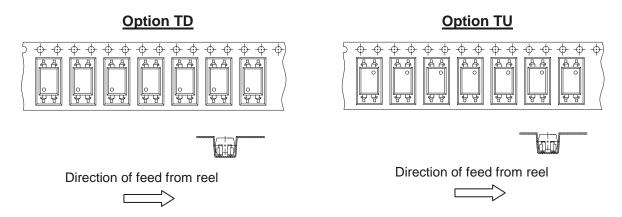
EL	denotes EVERLIGHT
817	denotes Device Number

F denotes Factory Code (G: China and Green part)
R denotes CTR Rank (A, B, C, D, X, Y or none)

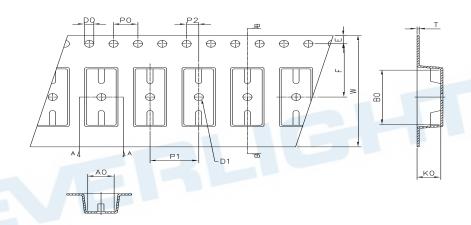
Y denotes 1 digit Year code WW denotes 2 digit Week code V denotes VDE (optional)



**Tape & Reel Packing Specifications** 



## **Tape dimensions**



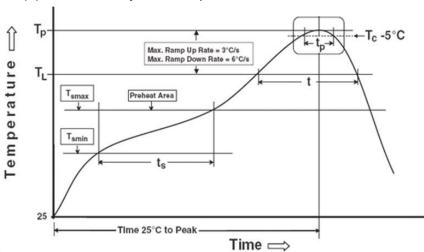
Dimension No.	Ao	Во	Do	D1	E	F
Dimension (mm) S1	4.90±0.1	10.40±0.1	1.5±0.1	1.50±0.1	1.75±0.1	7.50±0.1
Dimension (mm) S2	4.88±0.1	12.55±0.1	1.5±0.1	1.50±0.1	1.75±0.1	11.5±0.1
Dimension No.	Ро	P1	P2	t	w	Ко
Dimension No.  Dimension (mm) S1	Po 4.00±0.1	P1 8.00±0.1	P2 2.00±0.1	t 0.40±0.1	W 16.00±0.3	<b>Ko</b> 4.60±0.1



#### **Precautions for Use**

#### 1. Soldering Condition

1.1 (A) Maximum Body Case Temperature Profile for evaluation of Reflow Profile



Note:

#### **Preheat**

Temperature min  $(T_{smin})$ 

Temperature max (T<sub>smax</sub>)

Time  $(T_{smin} \text{ to } T_{smax})$   $(t_s)$ 

Average ramp-up rate (T<sub>smax</sub> to T<sub>p</sub>)

Other

Liquidus Temperature (T<sub>L</sub>)

Time above Liquidus Temperature (t L)

Peak Temperature (T<sub>P</sub>)

Time within 5 °C of Actual Peak Temperature: T<sub>P</sub> - 5°C

Ramp- Down Rate from Peak Temperature

Time 25°C to peak temperature

Reflow times

Reference: IPC/JEDEC J-STD-020D

150 °C

200°C

60-120 seconds

3 °C/second max

217 °C

60-100 sec

260°C

30 s

6°C /second max.

8 minutes max.

3 times



#### **DISCLAIMER**

- 1. Above specification may be changed without notice. EVERLIGHT will reserve authority on material change for above specification.
- 2. The graphs shown in this datasheet are representing typical data only and do not show guaranteed values.
- 3. When using this product, please observe the absolute maximum ratings and the instructions for use outlined in these specification sheets. EVERLIGHT assumes no responsibility for any damage resulting from use of the product which does not comply with the absolute maximum ratings and the instructions included in these specification sheets.
- 4. These specification sheets include materials protected under copyright of EVERLIGHT. Reproduction in any form is prohibited without the specific consent of EVERLIGHT.
- 5. This product is not intended to be used for military, aircraft, automotive, medical, life sustaining or life saving applications or any other application which can result in human injury or death. Please contact authorized Everlight sales agent for special application request.
- 6. Statements regarding the suitability of products for certain types of applications are based on Everlight's knowledge of typical requirements that are often placed on Everlight products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Everlight's terms and conditions of purchase, including but not limited to the warranty expressed therein.

## **X-ON Electronics**

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Photodiode Output Optocouplers category:

Click to view products by Everlight manufacturer:

Other Similar products are found below:

TLP590B(C,F) TLP5214(D4.E(O TLP7820(A-LF4.E(O EL817MB EL817S1(B)(TU)-FV EL357NB LTV-244-GB-G ORPC-817SB-TP-C OR-357D OR-357B-S-TP-G OR-3H4-4GB-TA1-GK OR-3H7-4GB-TA1-GK OR-M501-TP-G OR-3H5-TP-G OR-3H4B-TP-G OR-357C-S-TP-G PC817X3NIPW PC817X2YSZW SL-1008 SL-1009 PC817C LTV-354T PC817C PC357C LTV-356T-C SL-1007 PC817X2YIPW OR-3H4A-TP-G PC817C-S ORPC-815-C ORPC-852 OR-M611-TP-G ORPC-815S PS2701-1-L UPC817XG-D04-T LTV2301GB-V-G TLP621GB-1S KPC452 0E EL817(D)-FG EL817S1B(F) EL817M(C)(TH)-F IS281 APV2111V APV1121SX APV2111VY TLP3906(TPL,E TLP591B(C,F) TLP3905(E IS281GR APS1241S